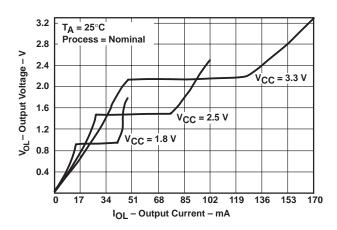
SCES166H - DECEMBER 1998 - REVISED JUNE 2000

- Member of the Texas Instruments Widebus™ Family
- EPIC[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- DOC[™] (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Dynamic Drive Capability Is Equivalent to Standard Outputs With I_{OH} and I_{OL} of ±24 mA at 2.5-V V_{CC}

- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class I
- Packaged in Thin Shrink Small-Outline Package

description

A Dynamic Output Control (DOC) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V_{OL} vs I_{OL} and V_{OH} vs I_{OH} curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, AVC Logic Family Technology and Applications, literature number SCEA006, and Dynamic Output Control (DOCTM) Circuitry Technology and Applications, literature number SCEA009.



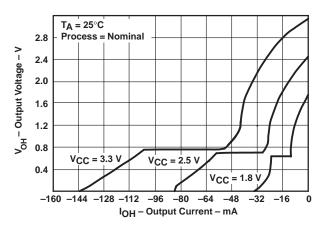


Figure 1. Output Voltage vs Output Current

This 22-bit flip-flop is operational at 1.2-V to 3.6-V V_{CC} , but is designed specifically for 1.65-V to 3.6-V V_{CC} operation.

The 22 flip-flops of the SN74AVC16722 are edge-triggered D-type flip-flops with clock-enable (CLKEN) input. On the positive transition of the clock (CLK) input, the device stores data into the flip-flops if CLKEN is low. If CLKEN is high, no data is stored.

A buffered output-enable (OE) input places the 22 outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. OE does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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description (continued)

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74AVC16722 is characterized for operation from -40°C to 85°C.

terminal assignments

DGG PACKAGE (TOP VIEW) <u>oe</u> II 64 **∏** CLK Q1 [] 2 63 D1 Q2 [] 3 62 D2 GND ∏ 4 61 ∏ GND Q3 🛮 5 60 D3 Q4 Π 6 59 **D** D4 V_{CC} **□** 7 58 V_{CC} Q5 🛮 8 57 D5 Q6 🛮 9 56 **∏** D6 Q7 [] 10 55 D7 GND [] 11 54 GND Q8 **∏** 12 53 D8 52 D9 Q9 **∏** 13 Q10 14 51 D10 Q11 [] 15 50 D11 Q12 16 49 D12 Q13 17 48 D13 GND [] 18 47 **∏** GND Q14 19 46 D14 Q15 20 45 D15 Q16 21 44 **∏** D16 V_{CC} 22 43 V_{CC} Q17 23 42 D17 Q18 24 41 **□** D18 GND ∏ 25 40 | GND Q19 **∏** 26 39 D19 Q20 **2**7 38 D20 V_{CC} **1** 28 37 V_{CC} Q21 [] 29 36 D21 Q22 | 30 35 **□** D22 GND [] 31 34 | GND NC 32 33 CLKEN

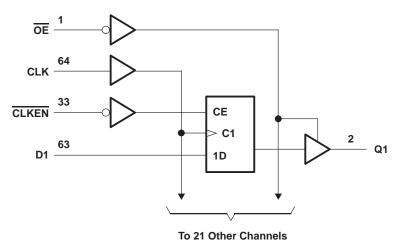
NC - No internal connection



FUNCTION TABLE (each flip-flop)

	INPL	OUTPUT		
OE	CLKEN	CLK	D	Q
L	Н	Х	Х	Q ₀
L	L	\uparrow	Н	Н
L	L	\uparrow	L	L
L	L	L or H	Χ	Q ₀
Н	Х	X	Χ	Z

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}
Input voltage range, V _I (see Note 1)
Voltage range applied to any output in the high-impedance or power-off state, VO
(see Note 1)
Voltage range applied to any output in the high or low state, VO
(see Notes 1 and 2)
Input clamp current, I_{IK} ($V_I < 0$)
Output clamp current, I_{OK} ($V_O < 0$)
Continuous output current, IO ±50 mA
Continuous current through each V _{CC} or GND ±100 mA
Package thermal impedance, θ_{JA} (see Note 3)
Storage temperature range, T _{stg} –65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.



recommended operating conditions (see Note 4)

			MIN	MAX	UNIT		
\/	Cumpluyaltaga	Operating	1.4	3.6	V		
Vcc	Supply voltage	Data retention only	1.2		V		
		V _{CC} = 1.2 V	VCC				
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	0.65 × V _{CC}				
VIH	High-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		V		
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7				
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2				
		V _{CC} = 1.2 V		GND			
		V _{CC} = 1.4 V to 1.6 V		0.35 × V _{CC}			
VIL	Low-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V		
		V _{CC} = 2.3 V to 2.7 V		0.7			
		V _{CC} = 3 V to 3.6 V		0.8			
٧ _I	Input voltage		0	3.6	V		
\/o	Output voltage	Active state	0	VCC	V		
Vo	Output voltage	3-state	0	3.6	V		
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		-2			
1000	Static high-level output current	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		-4	mA		
lons	Static high-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-8	mA		
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		-12			
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2			
	Static low-level output current†	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		4	mA		
lors	Static low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		8	IIIA		
		V _{CC} = 3 V to 3.6 V	12				
Δt/Δν	Input transition rise or fall rate	V _{CC} = 1.4 V to 3.6 V		5	ns/V		
TA	Operating free-air temperature		-40	85	°C		

[†] Dynamic drive capability is equivalent to standard outputs with I_{OH} and I_{OL} of ±24 mA at 2.5-V V_{CC}. See Figure 1 for V_{OL} vs I_{OL} and V_{OH} vs I_{OH} characteristics. Refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number **SCEA006**, and *Dynamic Output Control (DOC™) Circuitry Technology and Applications*, literature number **SCEA009**.

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST (CONDITIONS	VCC	MIN	TYP [†]	MAX	UNIT	
		I _{OHS} = -100 μA		1.4 V to 3.6 V	V _{CC} -0.2				
		$I_{OHS} = -2 \text{ mA},$	V _{IH} = 0.91 V	1.4 V	1.05				
Vон		$I_{OHS} = -4 \text{ mA},$	V _{IH} = 1.07 V	1.65 V	1.2			V	
		$I_{OHS} = -8 \text{ mA},$	V _{IH} = 1.7 V	2.3 V	1.75				
		$I_{OHS} = -12 \text{ mA},$	V _{IH} = 2 V	3 V	2.3				
		I _{OLS} = 100 μA		1.4 V to 3.6 V			0.2		
		$I_{OLS} = 2 \text{ mA},$	$V_{IL} = 0.49 V$	1.4 V			0.4		
VOL		$I_{OLS} = 4 \text{ mA},$	$V_{IL} = 0.57 V$	1.65 V			0.45	V	
		$I_{OLS} = 8 \text{ mA},$	$V_{IL} = 0.7 V$	2.3 V			0.55		
		$I_{OLS} = 12 \text{ mA},$	V _{IL} = 0.8 V	3 V					
П		$V_I = V_{CC}$ or GND		3.6 V			±2.5	μΑ	
I _{off}		V_I or $V_O = 3.6 V$		0			±10	μΑ	
loz		$V_O = V_{CC}$ or GND		3.6 V			±10	μΑ	
Icc		$V_I = V_{CC}$ or GND,	IO = 0	3.6 V			40	μΑ	
	Control inputs			2.5 V		4			
Ci	Control inputs	$V_I = V_{CC}$ or GND		3.3 V		4		pF	
	Data inputs	Al = ACC or GIAD		2.5 V		2		ρı-	
	Data inputs			3.3 V		2			
C	Outputs	Vo = Voo or GND	Va Va a or CND			6.5		pF	
Co	Outputs	VO = VCC or GND	V _O = V _{CC} or GND			6		РΓ	

[†] Typical values are measured at $T_A = 25$ °C.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)

			V _{CC} =	1.2 V	V _{CC} =		UNIT							
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
fclock	Clock freque	ency						80		140		175	MHz	
t _W	Pulse durati	on, CLK high or low					6.2		3.5		2.8		ns	
	Cotup time	Data before CLK↑	12.8		8.3		5.7		3.5		2.5			
tsu	Setup time	CLKEN before CLK↑	3.5		2		1.6		1.4		1.4		ns	
4.	l lald time	Data after CLK↑	0		0		0		0		0			
t _h	Hold time	CLKEN after CLK↑	2.1		1.6		1.3		1.2		1.2		ns	

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)

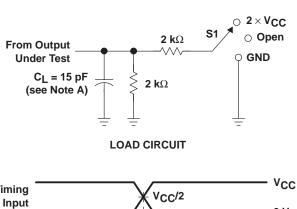
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.2 V	V _{CC} =	1.5 V I V	V _{CC} = ± 0.1		V _{CC} =		V _{CC} =		UNIT
	(1141 01)	(001101)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}							80		140		175	MHz
t _{pd}	CLK	Q	7.7	1.5	6.3	1.5	5.4	1	3.3	0.7	2.6	ns
ten	ŌĒ	Q	11.2	2.5	10.6	2.4	9.5	1.8	6	1.4	4.3	ns
t _{dis}	ŌĒ	Q	6.8	1.9	7.2	1.9	7	1.2	3.6	1.2	3.4	ns



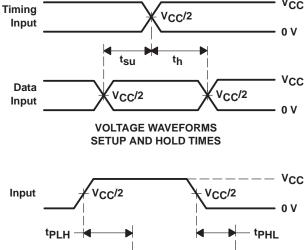
operating characteristics, T_A = 25°C

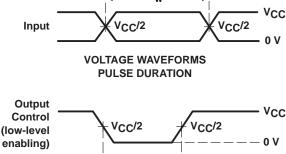
	PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V	$V_{CC} = 2.5 \text{ V}$	V _{CC} = 3.3 V	UNIT	
	FARAMETER		TEST CONDITIONS	TYP	TYP	TYP	ONT	
	Power dissipation	Outputs enabled	Cı = 0. f = 10 MHz	88	98	110	nE.	
Cpd	capacitance	Outputs disabled	$C_L = 0$, $f = 10 MHz$	60	64	79	p⊦	

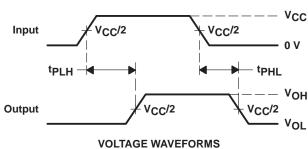
PARAMETER MEASUREMENT INFORMATION V_{CC} = 1.2 V AND 1.5 V \pm 0.1 V



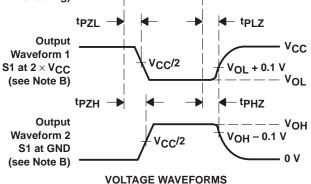








PROPAGATION DELAY TIMES



ENABLE AND DISABLE TIMES

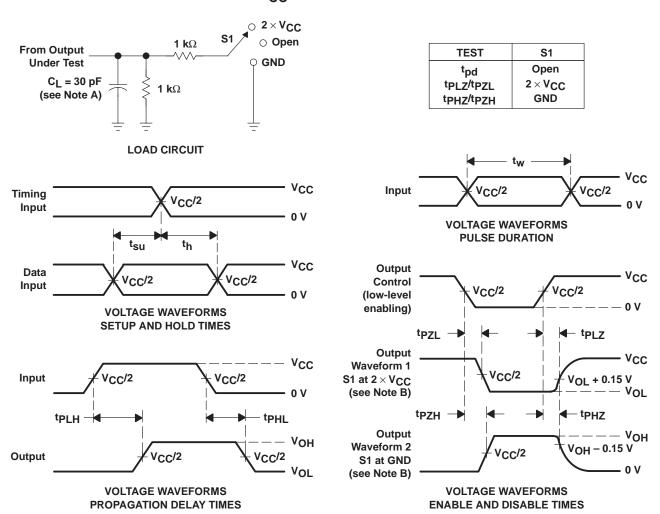
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpZL and tpZH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$

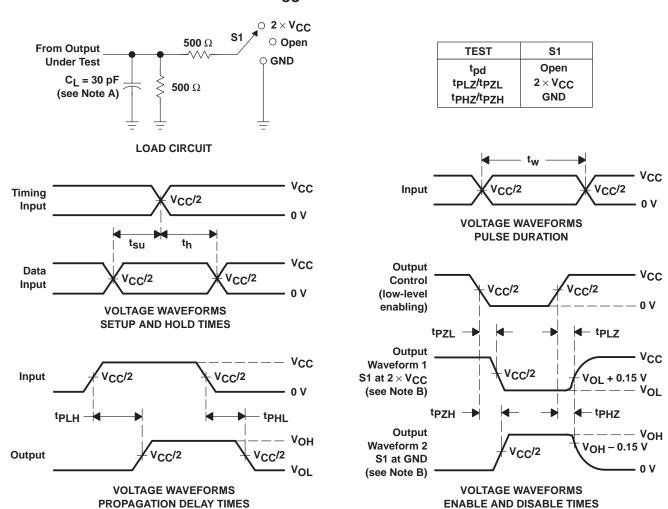


NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f \leq$ 2 ns. $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

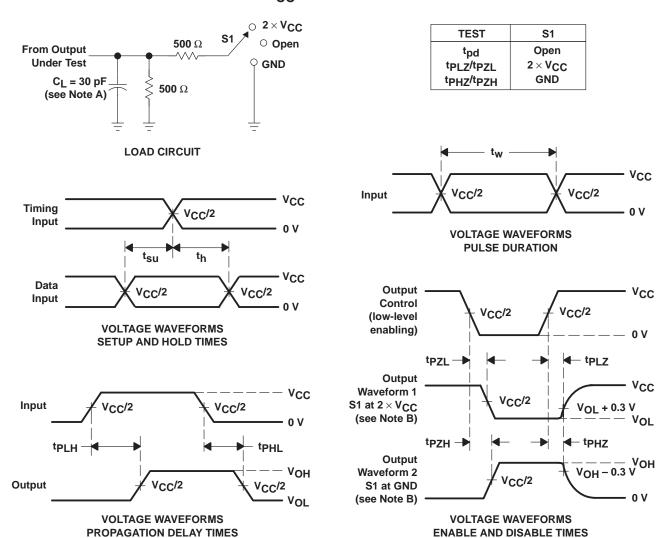


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 4. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



- NOTES: A. C_I includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpl 7 and tpH7 are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tplH and tpHL are the same as tpd.

Figure 5. Load Circuit and Voltage Waveforms







com 27-Sep-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins I	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74AVC16722DGGRE4	ACTIVE	TSSOP	DGG	64	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AVC16722DGGRG4	ACTIVE	TSSOP	DGG	64	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC16722DGGR	ACTIVE	TSSOP	DGG	64	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

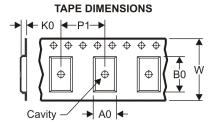
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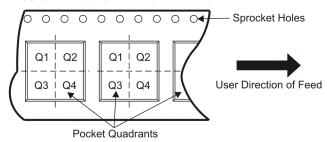
TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
		Overall width of the carrier tape
Γ	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC16722DGGR	TSSOP	DGG	64	2000	330.0	24.4	8.4	17.3	1.7	12.0	24.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC16722DGGR	TSSOP	DGG	64	2000	346.0	346.0	41.0

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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